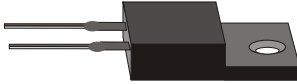


SFF81 THRU SFF87

GW

8.0 AMP SUPER FAST RECTIFIERS



FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability
- * Good for switching mode application

MECHANICAL DATA

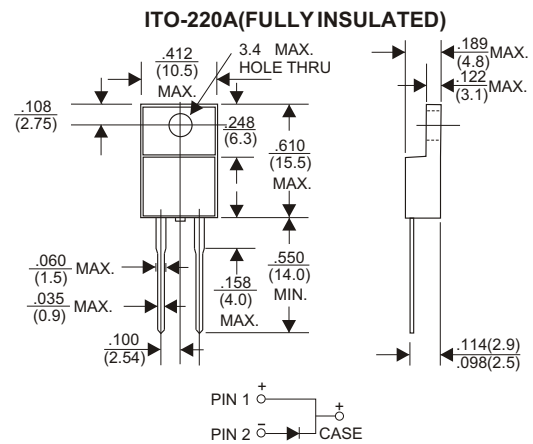
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Lead solderable per MIL-STD-202, method 208 guaranteed
- * Polarity: As Marked
- * Mounting position: Any

VOLTAGE RANGE

50 to 600 Volts

CURRENT

8.0 Amperes



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

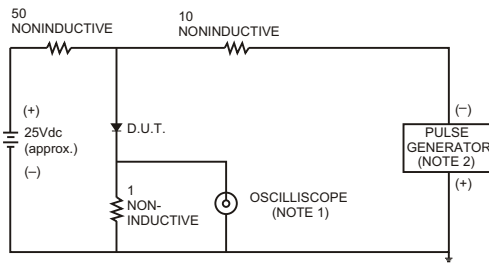
TYPE NUMBER	SF81	SF82	SF83	SF84	SF85	SF86	SF87	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	150	200	300	400	600	V
Maximum RMS Voltage	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at Tc=100°C	8.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	125							A
Maximum Instantaneous Forward Voltage at 8.0A	1.0				1.3		1.7	V
Maximum DC Reverse Current Tc=25°C	10							μA
at Rated DC Blocking Voltage Tc=100°C	500							μA
Maximum Reverse Recovery Time (Note 1)	35				50			nS
Typical Junction Capacitance (Note 2)	50							PF
Typical Thermal Resistance RθJC	3.0							°C/W
Operating and Storage Temperature Range Tj, Tstg	-65 — +150							°C

NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (SFF81 THRU SFF87)

FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

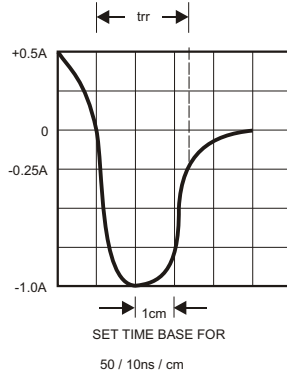


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

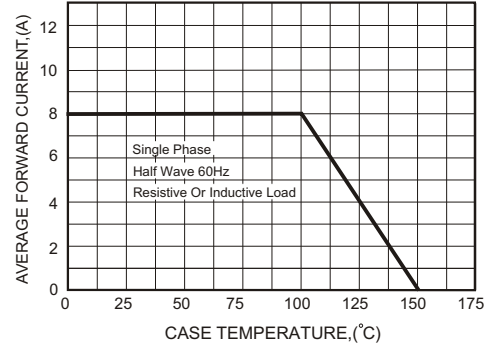


FIG.3-TYPICAL FORWARD CHARACTERISTICS

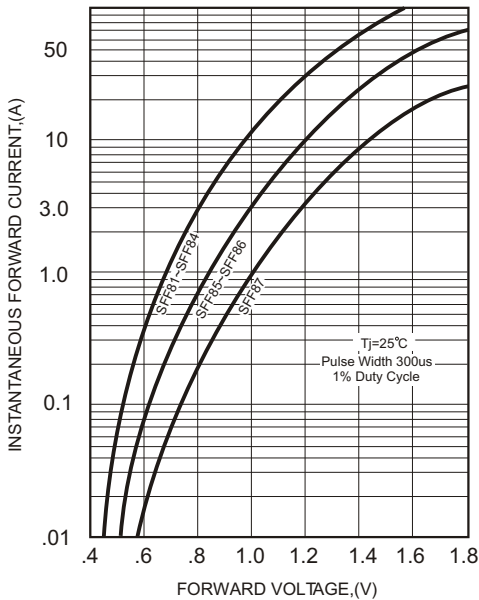


FIG.4-TYPICAL REVERSE CHARACTERISTICS

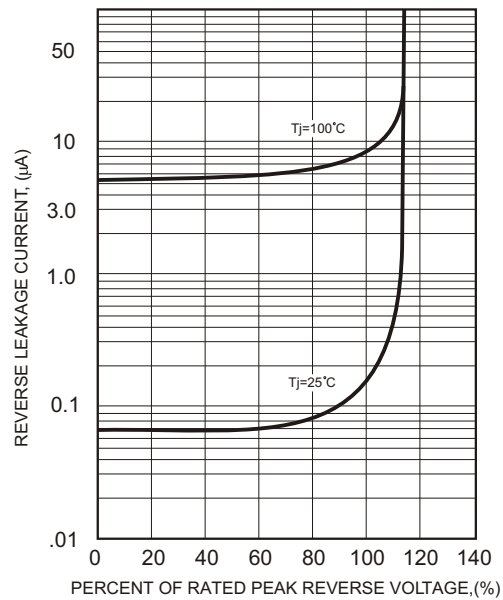


FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

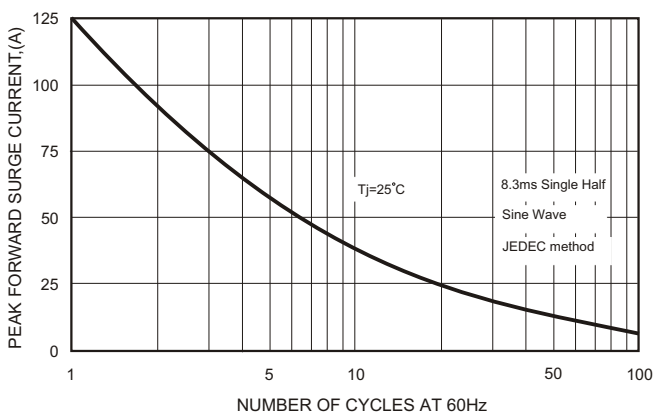
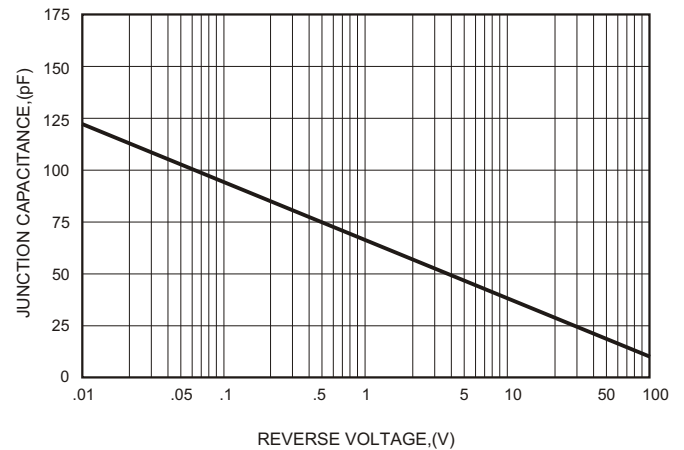


FIG.6-TYPICAL JUNCTION CAPACITANCE



SFF101CT THRU SFF107CT

GW

10.0 AMP SUPER FAST RECTIFIERS



FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability
- * Good for switching mode application

MECHANICAL DATA

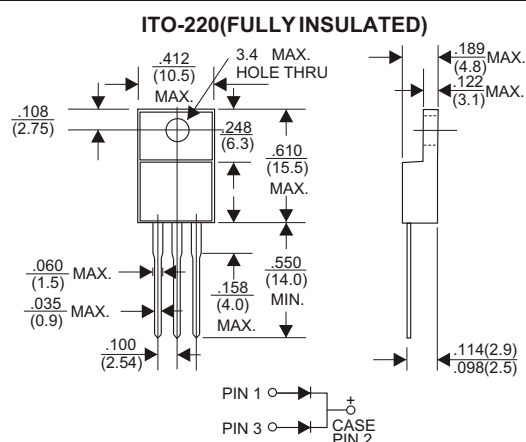
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Lead solderable per MIL-STD-202, method 208 guaranteed
- * Polarity: As Marked
- * Mounting position: Any

VOLTAGE RANGE

50 to 600 Volts

CURRENT

10.0 Amperes



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

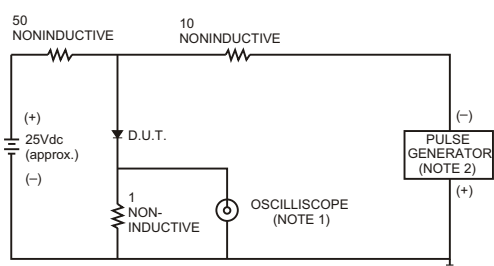
TYPE NUMBER	SFF 101CT	SFF 102CT	SFF 103CT	SFF 104CT	SFF 105CT	SFF 106CT	SFF 107CT	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	150	200	300	400	600	V
Maximum RMS Voltage	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at Tc=100°C	10.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	125							A
Maximum Instantaneous Forward Voltage at 5.0A	1.0				1.3		1.7	V
Maximum DC Reverse Current Tc=25°C	10							μA
at Rated DC Blocking Voltage Tc=100°C	500							μA
Maximum Reverse Recovery Time (Note 1)	35				50			nS
Typical Junction Capacitance (Note 2)	55							PF
Typical Thermal Resistance RθJC	3.0							°C/W
Operating and Storage Temperature Range Tj, Tstg	-65 — +150							°C

NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (SFF101CT THRU SFF107CT)

FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time = 7ns max., Input Impedance = 1 megohm. 22pF.
2. Rise Time = 10ns max., Source Impedance = 50 ohms.

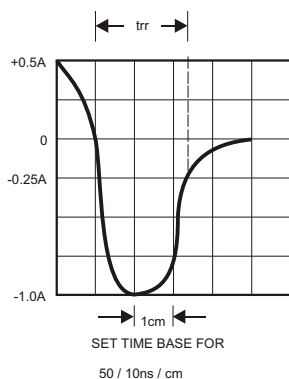


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

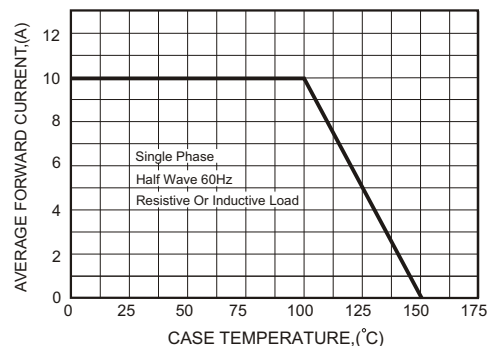


FIG.3-TYPICAL FORWARD CHARACTERISTICS

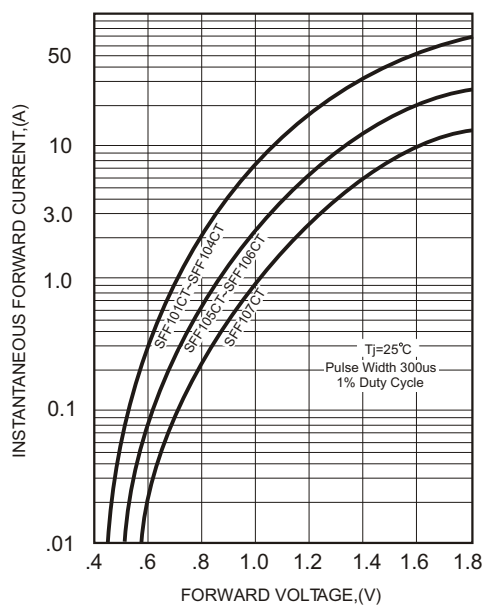


FIG.4-TYPICAL REVERSE CHARACTERISTICS

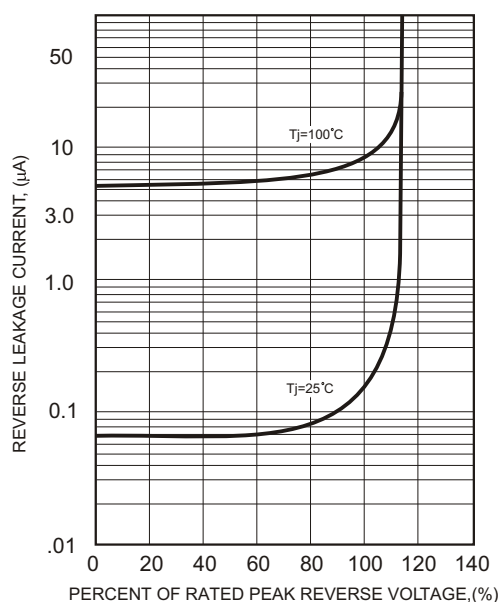


FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

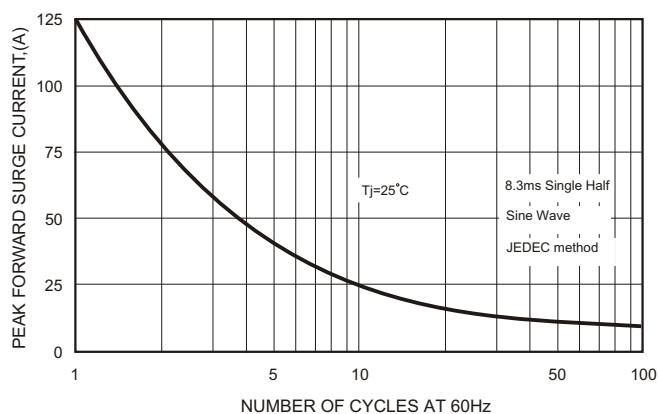
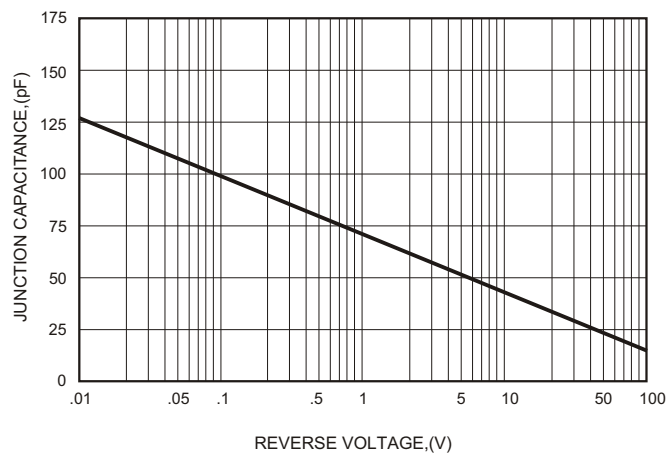


FIG.6-TYPICAL JUNCTION CAPACITANCE



SFF161CT THRU SFF167CT



16.0 AMP SUPER FAST RECTIFIERS



FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability
- * Good for switching mode application

MECHANICAL DATA

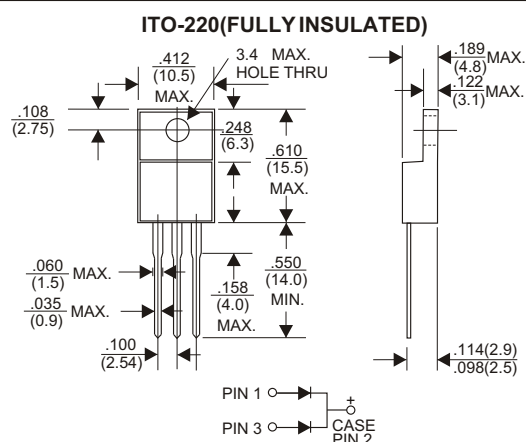
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Lead solderable per MIL-STD-202, method 208 guaranteed
- * Polarity: As Marked
- * Mounting position: Any

VOLTAGE RANGE

50 to 600 Volts

CURRENT

16.0 Amperes



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

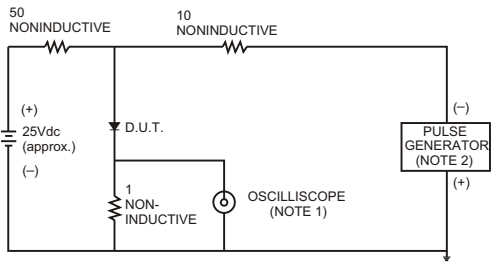
TYPE NUMBER	SFF 161CT	SFF 162CT	SFF 163CT	SFF 164CT	SFF 165CT	SFF 166CT	SFF 167CT	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	150	200	300	400	600	V
Maximum RMS Voltage	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at Tc=100°C	16.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	125							A
Maximum Instantaneous Forward Voltage at 8.0A	1.0				1.3		1.7	V
Maximum DC Reverse Current Tc=25°C	10							μA
at Rated DC Blocking Voltage Tc=100°C	500							μA
Maximum Reverse Recovery Time (Note 1)	35				50			nS
Typical Junction Capacitance (Note 2)	60							PF
Typical Thermal Resistance RθJC	2.5							°C/W
Operating and Storage Temperature Range Tj, Tstg	-65 — +150							°C

NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (SFF161CT THRU SFF167CT)

FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

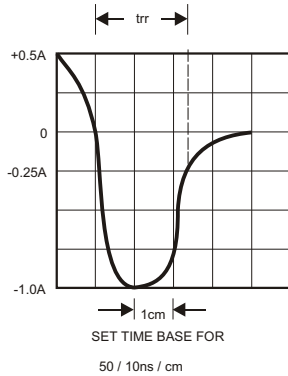


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

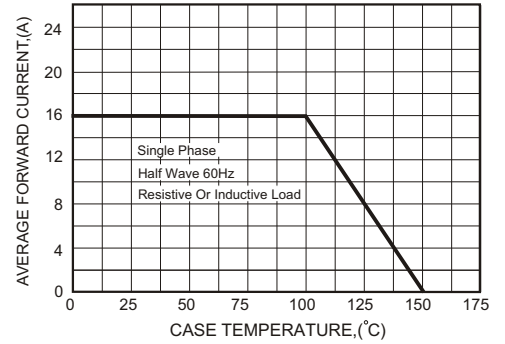


FIG.3-TYPICAL FORWARD CHARACTERISTICS

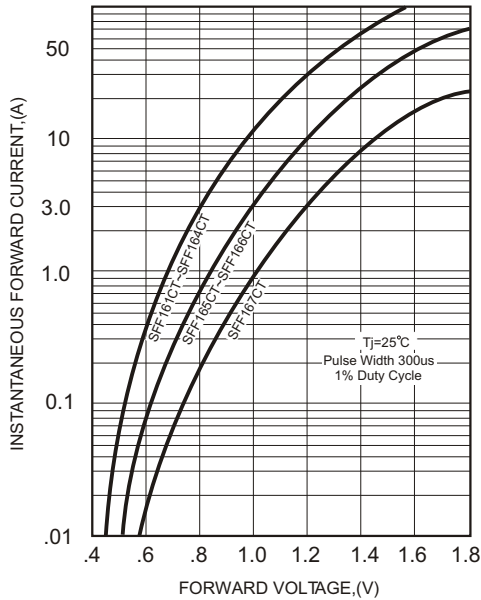


FIG.4-TYPICAL REVERSE CHARACTERISTICS

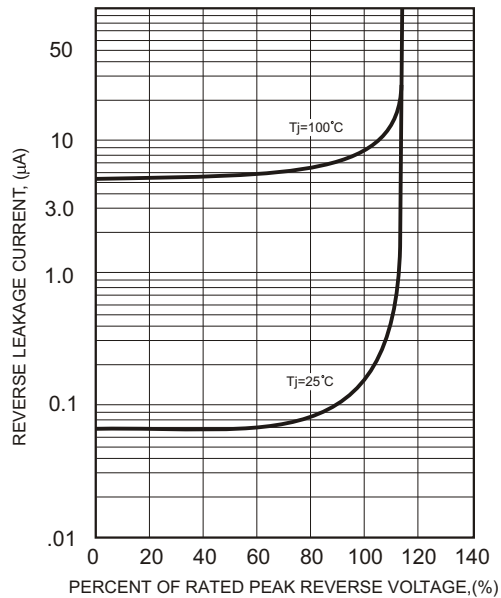


FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

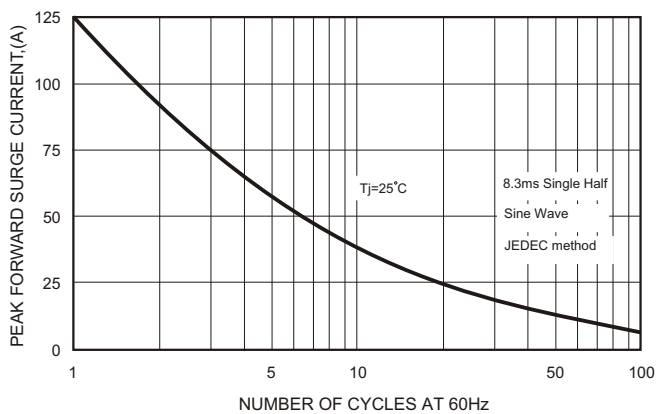


FIG.6-TYPICAL JUNCTION CAPACITANCE

